



(12) **EUROPEAN PATENT APPLICATION**

(43) Date of publication:  
**25.04.2007 Bulletin 2007/17**

(51) Int Cl.:  
**H01L 51/52 (2006.01)**

(21) Application number: **06255407.6**

(22) Date of filing: **20.10.2006**

(84) Designated Contracting States:  
**AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HU IE IS IT LI LT LU LV MC NL PL PT RO SE SI SK TR**  
Designated Extension States:  
**AL BA HR MK YU**

(72) Inventor: **Lee, Kwan Hee,**  
**c/o Samsung SDI Co., Ltd.**  
**Yongin-si**  
**Gyeonggi-do (KR)**

(30) Priority: **20.10.2005 KR 20050099381**

(74) Representative: **Mouteney, Simon James**  
**Marks & Clerk**  
**90 Long Acre**  
**London WC2E 9RA (GB)**

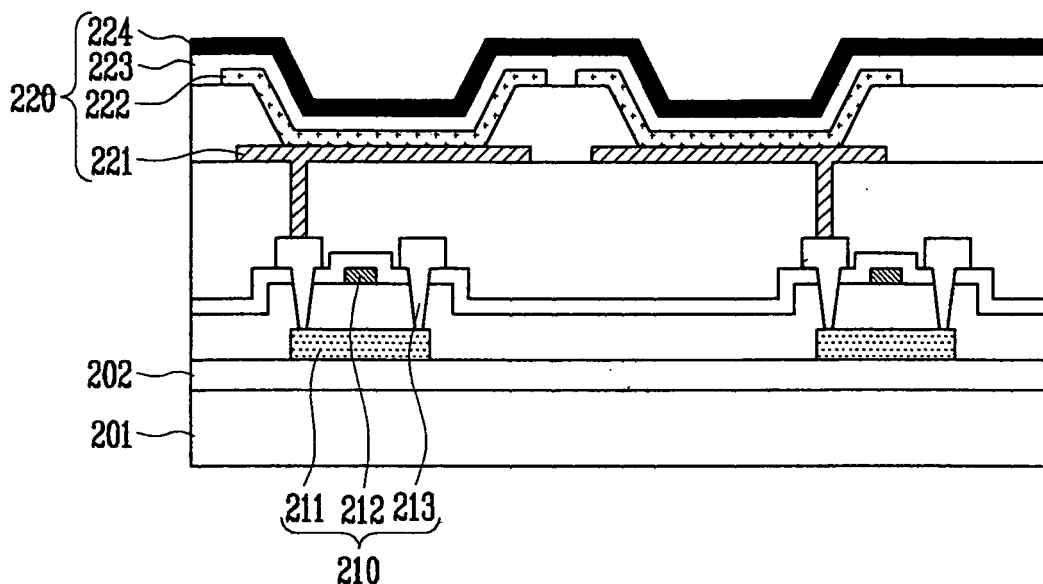
(71) Applicant: **Samsung SDI Co., Ltd.**  
**Suwon-si,**  
**Gyeonggi-do (KR)**

(54) **Organic light emitting display, method of fabricating the same, and mobile display including the organic light emitting display**

(57) An organic light emitting display and a method of fabricating the same. The organic light emitting display may include a transistor (210) on a substrate, a lower electrode (221) on the substrate, the lower electrode being electrically connected to the transistor, an organic

light emitting layer (222) on the lower electrode, an upper electrode (223) on the organic light emitting layer, and a buffer layer (224) formed on the upper electrode to modify a predetermined thickness of the upper electrode to be a non-conductive material.

**FIG. 1**



## Description

### BACKGROUND OF THE INVENTION

#### 1. Field of the Invention

[0001] The present invention relates to an organic light emitting display, a method of fabricating the same, and a mobile display including the organic light emitting display. More particularly, the present invention relates to an organic light emitting display that is capable of preventing a dark point from being generated, a method of fabricating the same, and a mobile display including the organic light emitting display.

#### 2. Description of the Related Art

[0002] A conventional organic light emitting display (OLED) may include a light emitting unit 120, as illustrated in FIG. 10, to be electrically connected to, e.g., a thin film transistor (TFT) (not shown) on a substrate 100. The light emitting unit 120 may include a lower electrode 121, an organic light emitting layer 122, and an upper electrode 123.

[0003] In the conventional OLED having the above-described structure, as illustrated in FIG. 10, the organic light emitting layer 122 may not be uniformly deposited due, e.g., to particles that may exist on the lower electrode 121. Therefore, the upper electrode 123 may be connected to the lower electrode 121 at a junction where the particles exist. Therefore, the light emitting unit 120 may short circuit, resulting in a dark spot. As a result, a light emitting region may be reduced, deteriorating picture quality.

### SUMMARY OF THE INVENTION

[0004] The present invention is therefore directed to an organic light emitting display, a method of fabricating the same, and a mobile display including the organic light emitting display, which substantially overcome one or more of the problems due to the limitations and disadvantages of the related art.

[0005] It is therefore an object of an embodiment of the present invention to insulate the upper and lower electrodes from each other to prevent a dark spot from being generated.

[0006] Embodiments of the invention therefore set out to provide a buffer layer on the upper electrode that can render a predetermined thickness of the upper electrode non-conductive.

[0007] Embodiments of the invention also set out to provide an organic light emitting display that is capable of reducing or preventing a dark spot from being generated.

[0008] Embodiments of the invention also set out to provide a method of fabricating an organic light emitting display that is capable of reducing or preventing a dark

spot from being generated.

[0009] Embodiments of the invention also set out to provide a mobile display including the organic light emitting display that is capable of reducing or preventing a dark spot from being generated.

[0010] At least one of the above and other features and advantages of the present invention maybe realized by providing an organic light emitting display, including a transistor on a substrate, a lower electrode on the substrate, the lower electrode being electrically connected to the transistor, an organic light emitting layer on the lower electrode, an upper electrode on the organic light emitting layer, and a buffer layer formed on the upper electrode to modify a predetermined thickness of the upper electrode to be non-conductive material.

[0011] The buffer layer may be about 10Å to 100Å thick. The predetermined thickness of the upper electrode may be about 10Å to 30Å. The non-conductive material of the predetermined thickness may be an oxide.

[0012] The buffer layer may be a polyol-based buffer layer. The polyol of which the polyol-based buffer layer may be formed may be a compound including at least two OH groups in one molecule.

[0013] The upper electrode may have a smaller work function than the lower electrode.

[0014] The organic light emitting display may include at least one protective layer on the buffer layer. The protective layer may be a passivation layer or a capping layer.

[0015] The organic light emitting layer may include at least one organic layer having at least one of a hole injecting layer, a hole transporting layer, an electron transporting layer, and an electron injecting layer.

[0016] At least one of the above and other features and advantages may be realized by providing a method of fabricating an organic light emitting display, the method including forming a lower electrode electrically connected to a transistor on a substrate, forming an organic light emitting layer on the lower electrode, forming an upper electrode on the organic light emitting layer, and forming a buffer layer on the upper electrode in order to modify a predetermined thickness of the upper electrode to be a non-conductive material.

[0017] At least one of the above and other features and advantages may be realized by providing a mobile display including a display main body having a picture unit for displaying a picture, the picture unit including an organic light emitting display having any of the above elements.

### BRIEF DESCRIPTION OF THE DRAWINGS

[0018] Embodiments of the invention will now be described by way of example and with reference to the accompanying drawings, in which:-

[0019] FIG. 1 is a cross-sectional view of an organic light emitting display according to a first embodiment of the present invention;

**[0020]** FIG. 2 is a cross-sectional view of an organic light emitting display according to a second embodiment of the present invention;

**[0021]** FIG. 3 is a cross-sectional view of an organic light emitting display according to a third embodiment of the present invention;

**[0022]** FIG. 4 is a cross-sectional view of an organic light emitting display according to a fourth embodiment of the present invention;

**[0023]** FIG. 5 is a cross-sectional view of an organic light emitting display according to a fifth embodiment of the present invention;

**[0024]** FIG. 6 is a cross-sectional view of an organic light emitting display according to a sixth embodiment of the present invention;

**[0025]** FIG. 7 is a detailed schematic cross-sectional diagram of a light emitting unit according to embodiments of the present invention;

**[0026]** FIG. 8 is as schematic a mobile display including an organic light emitting display according to an embodiment of the present invention;

**[0027]** FIG. 9 is an enlarged cross-sectional view of part A of FIG. 8; and

**[0028]** FIG. 10 is a detailed schematic cross-sectional diagram of a conventional light emitting unit for use in a conventional organic light emitting display.

## DETAILED DESCRIPTION THE INVENTION

**[0029]** The present invention will now be described more fully hereinafter with reference to the accompanying drawings, in which various embodiments of the invention are illustrated. The invention may, however, be embodied in different forms and should not be construed as limited to the embodiments set forth herein.

**[0030]** In the figures, the dimensions of layers and regions may be exaggerated for clarity of illustration. It will also be understood that when a layer or element is referred to as being "on" another layer or substrate, it can be directly on the other layer or substrate, or intervening layers may also be present. Further, it will be understood that when a layer is referred to as being "under" another layer, it can be directly under, and one or more intervening layers may also be present. In addition, it will also be understood that when a layer is referred to as being "between" two layers, it can be the only layer between the two layers, or one or more intervening layers may also be present. Like reference numerals refer to like elements throughout.

**[0031]** As discussed in detail below, upper and lower electrodes of a light emitting unit for use in an organic light emitting display (OLED) may be insulated from each other, even when an organic light emitting layer does not completely insulate these electrodes, in accordance with various configurations, thus reducing or preventing formation of a dark spot, improving image quality. By converting a predetermined thickness of an upper electrode into a non-conductive material, any inadvertent contact

between the upper and lower electrodes due to discontinuities in the organic light emitting layer may not resort in shorting the light emitting unit.

**[0032]** Referring to FIG. 1, an organic light emitting display (OLED) according to an embodiment of the present invention may include a thin film transistor (TFT) 210 formed on a substrate 201, and a light emitting unit 220. The TFT 210 may include a semiconductor layer 211, a gate electrode 212, and source-drain electrodes 213. The light emitting unit 220 may include a lower electrode 221 on the substrate electrically connected to the TFT 210, an organic light emitting layer 222 on the lower electrode, an upper electrode 223 on the organic light emitting layer, and a buffer layer, e.g., a polyol-based buffer layer 224, on the upper electrode 223. The polyol-based buffer layer 224 may render a predetermined thickness of the upper electrode to be non-conductive, i.e., may modify the predetermined thickness of the upper electrode to be a non-conductive material, e.g., to be an oxide.

**[0033]** In a first embodiment of the present invention, as illustrated in FIG. 1, the polyol-based buffer layer 224 may extend over an entire OLED structure, i.e., may be continuous. Alternatively, an OLED according to a second embodiment of the present invention, as illustrated in FIG. 2, a light emitting unit 220' may include a polyol-based buffer layer 224' that may only extend within a contact hole for each light emitting unit, i.e., may be discontinuous. All of the other elements of the OLED may be the same as those in FIG. 1, so discussion thereof will not be repeated.

**[0034]** Referring to FIGS. 3 and 4, an OLED according to third and fourth embodiments of the present invention may further include a capping layer 225 on the polyol-based buffer layer 224, 224' of FIGS. 2 and 3, respectively. All of the other elements of the OLED may be the same as those in FIGS. 2 and 3, so discussion thereof will not be repeated.

**[0035]** Referring to FIGS. 5 and 6, an OLED according to fifth and sixth embodiments of the present invention may further include a passivation layer 226 on the polyol-based buffer layer 224, 224' of FIGS. 2 and 3, respectively. All of the other elements of the OLED may be the same as those in FIGS. 1 and 2, respectively, so discussion thereof will not be repeated.

**[0036]** The thin film transistor 210 formed on the substrate 201 may be formed by a method that is common in the art to have a structure that is common in the art. For example, a buffer layer 202 may be selectively formed on the substrate 201. Then, a semiconductor layer 211, including source-drain regions, may be formed on the buffer layer. After forming a gate insulating layer on the substrate including the semiconductor layer 211 and forming a gate electrode 212 on the gate insulating layer, source-drain electrodes 213 connected to the source-drain regions through contact holes may be formed on the interlayer insulating layer to form the thin film transistor 210.

**[0037]** A light emitting unit 220 electrically connected

to the thin film transistor 210 may be formed on the substrate where the thin film transistor 210 is formed. To be specific, a lower electrode 221 may be electrically connected to one of the source-drain electrodes 213 of the thin film transistor 210 through a via hole formed on the passivation layer formed on the substrate 200.

**[0038]** A conventional substrate for an OLED, e.g., a glass substrate or a transparent plastic substrate having excellent transparency, surface flatness, and is easily dealt with and waterproof, may be used as the substrate 201.

**[0039]** The lower electrode 221 formed on the substrate may be an anode electrode or a cathode electrode, and may be a reflective electrode or a transmissive electrode in accordance with front surface emission or rear surface emission operation of the OLED.

**[0040]** The lower electrode 211 may be an anode electrode. When the lower electrode 221 is the anode electrode, the lower electrode 221 may be formed of a conductive material, e.g., a metal or an oxide, that has a high work function and into which holes may be easily injected, e.g., indium tin oxide (ITO), indium zinc oxide (IZO), Ni, Pt, Au, and Ir.

**[0041]** An organic light emitting layer 222 may be formed on the lower electrode 221. The organic light emitting layer 222 may include an emission layer and at least one organic layer in addition to the emission layer. The at least one organic layer may have at least one of a hole injecting layer, a hole transporting layer, a hole suppressing layer, an electron transporting layer, and an electron injecting layer. Any of the emission layer, the hole injecting layer, the hole transporting layer, the hole suppressing layer, the electron transporting layer, and the electron injecting layer may be formed with methods and materials commonly used in the art.

**[0042]** For example, the hole injecting layer may be formed of CuPc or Starburst type amine by deposition or spin coating, although not limited to the above. The hole transporting layer may be formed of materials having hole transporting properties, e.g., N'-diphenyl-N,N'-bis(3-methylphenyl) 1,1-biphenyl 4,4'-diamine (hereinafter, TPD) by deposition, spin coating, etc. The emission layer may be formed of light emitting materials, e.g., aluminum tris(8-hydroxyquinoline) (Alq3), by deposition, spin coating, etc. The electron transporting layer may be formed of oxadiazole-based derivative by deposition, spin coating, etc.

**[0043]** The upper electrode 223 may be formed on the organic light emitting layer 222. The upper electrode 223 may be an anode electrode or a cathode electrode. When the upper electrode 223 is the cathode electrode, the cathode electrode may be formed of metals, e.g., Li, Mg, Al, Al-Li, Ca, Mg-In, Mg-Ag, etc. Therefore, the structure of the light emitting unit 220, 220' may vary from the lower electrode/the organic light emitting layer/the upper layer to the lower electrode/the hole injecting layer/the hole transporting layer/the organic light emitting layer/the hole suppressing layer/the electron transporting layer/the

electron injecting layer/the upper electrode.

**[0044]** A polyol-based buffer layer 224 may be formed on the upper electrode 223 by a method such as deposition, spin coating, etc., under the conditions similar to those used for forming the above layers. As illustrated in FIG. 8, in order to prevent the upper electrode 223 from being shorted due to a connection between the upper electrode 223 and the lower electrode 221 that may arise when the organic light emitting layer 222 is not uniformly deposited, e.g., due to particles that may exist on the lower electrode 221, the polyol-based buffer layer 224 modifies a predetermined thickness of the upper electrode 223 to be non-conductive, so that the upper and lower electrodes are insulated from each other. In order to modify the predetermined thickness of the upper electrode to be non-conductive, the predetermined thickness of the upper electrode 223 may be modified, e.g., to be an oxide or a nitride.

**[0045]** The predetermined thickness of the upper electrode 223 may be modified to be a non-conductive oxide by forming the polyol-based buffer layer 224 on the upper electrode 223. That is, the -OH group of polyol may oxidize the metal of the upper electrode 223. In this case, oxidation occurs during formation of the -OH group of the polyol-based buffer layer 224, 224'.

**[0046]** The thickness of the polyol-based buffer layer 224, 224' may be about 10Å to 100Å. Due to the oxidation of the upper electrode by the buffer layer having this thickness, the predetermined thickness of the non-conductive oxide layer will be less than 100Å, e.g., between 10Å to 30Å. The polyol-based buffer layer 224, 224' may be formed on the upper electrode 223 or may surround the sides and the front surface of the upper electrode 223.

**[0047]** The polyol of which the buffer layer may be a compound having two or more -OH groups including, e.g., a monosaccharide such as glucose, fructose, mannose, galactose, or ribose, a disaccharide such as sucrose, maltose, or lactose, ethylene glycol, propylene glycol, 1,3-propandiol, 1,3-butanediol, 1,4-butanediol, 1,5-pentanediol, 1,6-hexanediol, neopentyl glycol, diethylene glycol, dipropylene glycol, triethylene glycol, tetraethylene glycol, dibutylene glycol, 2-methyl-1,3-pentanediol, 2,2,4-trimethyl-1,3-pentanediol, 1,4-cyclohexanediol, etc.

**[0048]** At least one protective layer for protecting the organic light emitting layer 222 may be formed on the polyol-based buffer layer 224, 224'. The capping layer 225 or the passivation layer 226 may be used as the protective layer. The capping layer 225 and the passivation layer 226 may be formed, e.g., by deposition or spin coating, transparent materials that are commonly used in the art.

**[0049]** Referring to FIGS. 8 and 9, a mobile display 1000 may include a picture unit 1100 for displaying a picture and a display main body including a plurality of operation button units 1200. As illustrated in the cross-sectional detail of FIG. 9, the OLED having the light emitting unit 220, 220' and the transistor 210 according to

any of the exemplary embodiments of the present invention may be provided in the picture unit 1100.

**[0050]** The OLED according to the present-invention may be applied to various displays, e.g., a personal digital assistant (PDA), an electronic pager, a video camera, a workstation, a picture telephone etc., besides the mobile telephone 1000 illustrated in FIG. 9.

**[0051]** As described above, according to the present invention, the polyol-based buffer layer may be formed on the upper electrode so that the predetermined thickness of the upper electrode is rendered non-conductive. Thus, even if the organic light emitting layer is non-uniformly deposited, e.g., due to particles that may exist on the lower electrode, only the non-conductive surface of the upper electrode will contact the lower electrode. Therefore, it is possible to prevent the light emitting unit from being shorted, to prevent the dark point from being generated, and to improve picture quality.

**[0052]** Embodiments of the present invention have been disclosed herein, and although specific terms are employed, they are used and are to be interpreted in a generic and descriptive sense only and not for purpose of limitation. Accordingly, it will be understood by those of ordinary skill in the art that various changes in form and details may be made without departing from the scope of the present invention as set forth in the following claims.

## Claims

### 1. An organic light emitting display, comprising:

a transistor on a substrate;  
a lower electrode on the substrate, the lower electrode being electrically connected to the transistor;  
an organic light emitting layer on the lower electrode;  
an upper electrode on the organic light emitting layer; and  
a buffer layer formed on the upper electrode to modify a predetermined thickness of the upper electrode to be a non-conductive material.

### 2. An organic light emitting display as claimed in claim 1, wherein a thickness of the buffer layer is about 10Å to 100Å.

### 3. An organic light emitting display as claimed in claim 1 or 2, wherein the predetermined thickness of the upper electrode is about 10Å to 30Å.

### 4. An organic light emitting display as claimed in claim 1, 2 or 3 wherein the buffer layer is a polyol-based buffer layer.

### 5. An organic light emitting display as claimed in claim

4, wherein polyol of which the polyol-based buffer layer is formed of a compound including at least two -OH groups.

### 6. An organic light emitting display as claimed in any preceding claim, wherein the upper electrode is a cathode.

### 7. An organic light emitting display as claimed in any preceding claim, further comprising at least one protective layer on the buffer layer.

### 8. An organic light emitting display as claimed in claim 7, wherein the protective layer is a passivation layer or a capping layer.

### 9. An organic light emitting display as claimed in any preceding claim, wherein the organic light emitting layer further comprises at least one organic layer including at least one of a hole injecting layer, a hole transporting layer, an electron transporting layer, and an electron injecting layer.

### 10. An organic light emitting display as claimed in any preceding claim, wherein the non-conductive material is an oxide.

### 11. A method of fabricating an organic light emitting display, the method comprising:

forming a lower electrode electrically connected to a transistor on a substrate;  
forming an organic light emitting layer on the lower electrode;  
forming an upper electrode on the organic light emitting layer; and  
forming a buffer layer on the upper electrode in order to modify a predetermined thickness of the upper electrode to be a non-conductive material.

### 12. A mobile display including a display main body having a picture unit for displaying a picture, the picture unit including an organic light emitting display as set out in one of claims 1 to 10.

FIG. 1

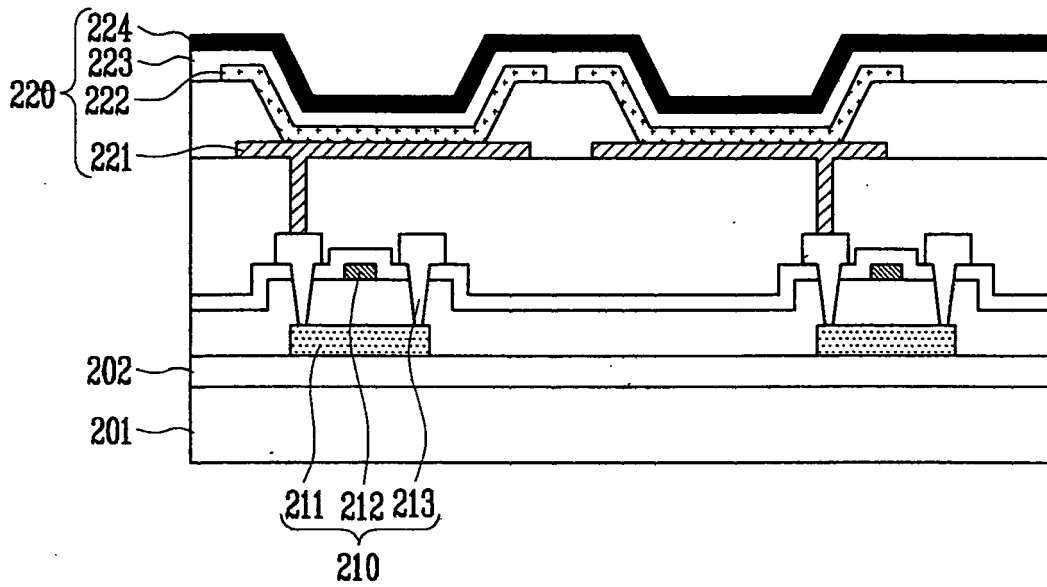


FIG. 2

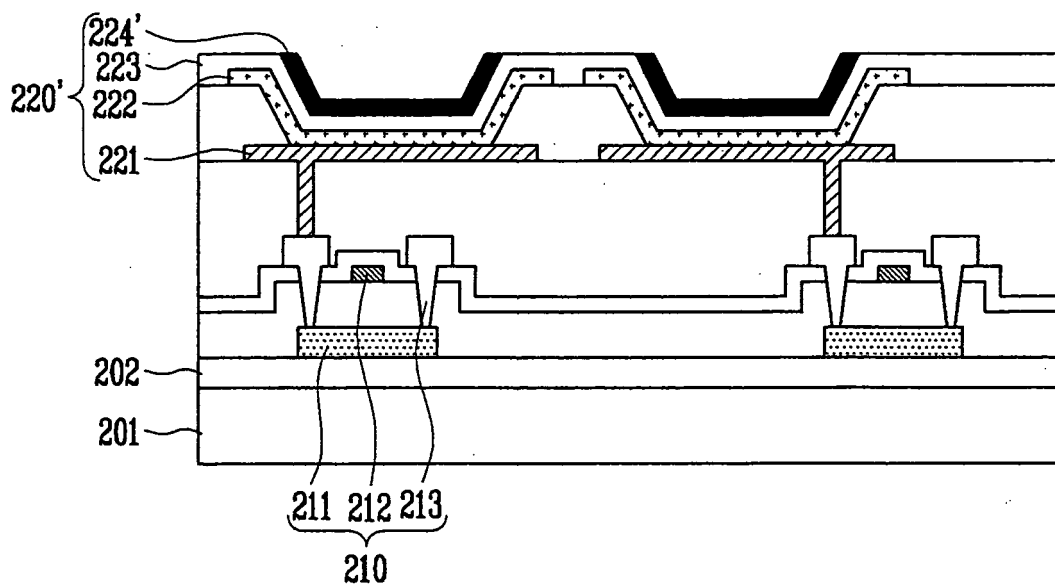


FIG. 3

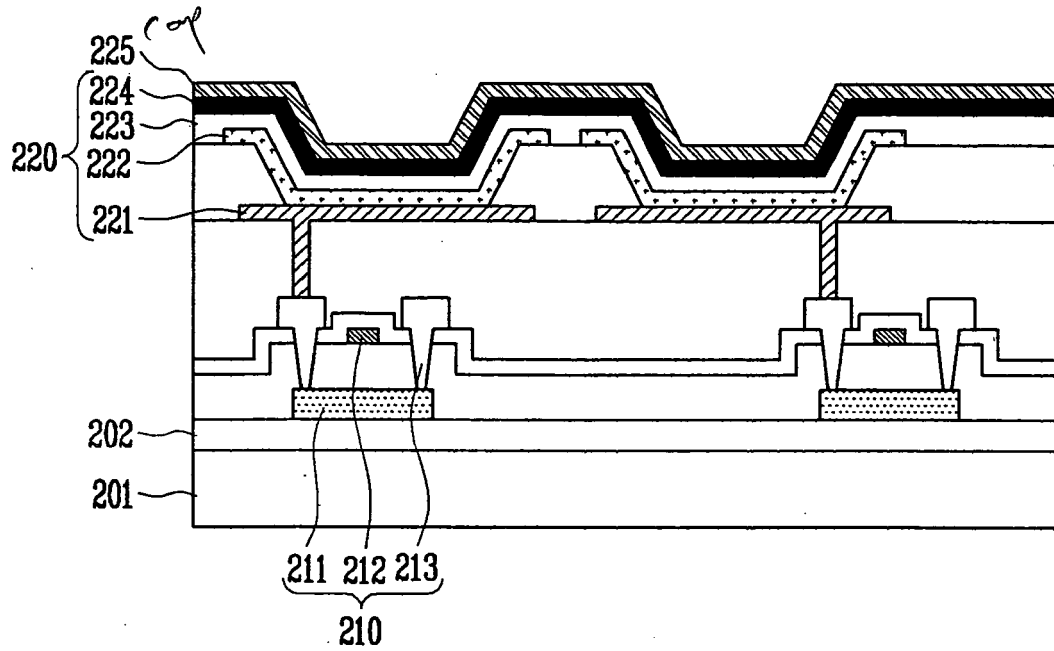


FIG. 4

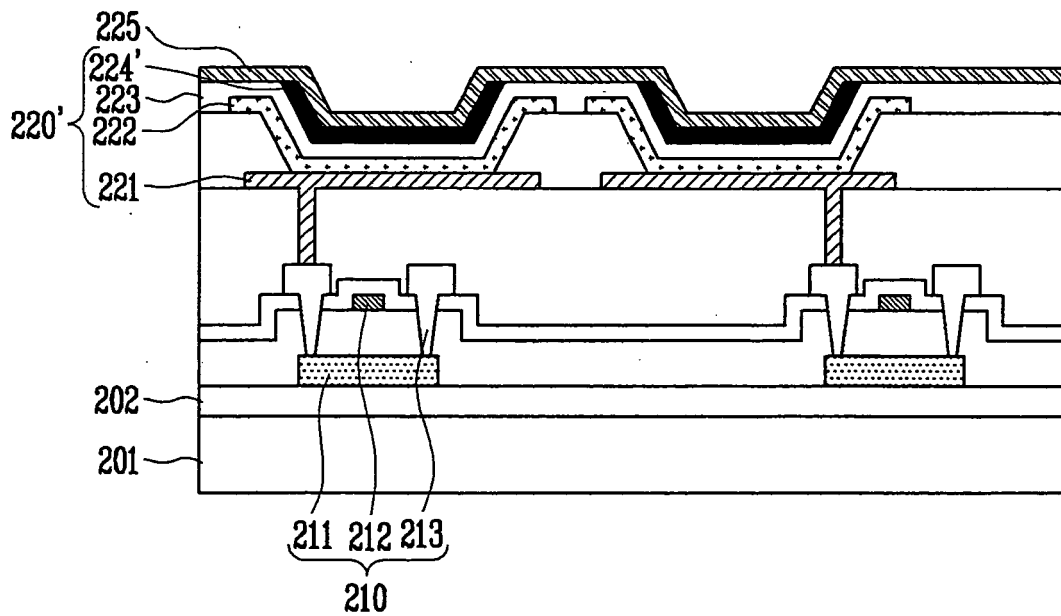


FIG. 5

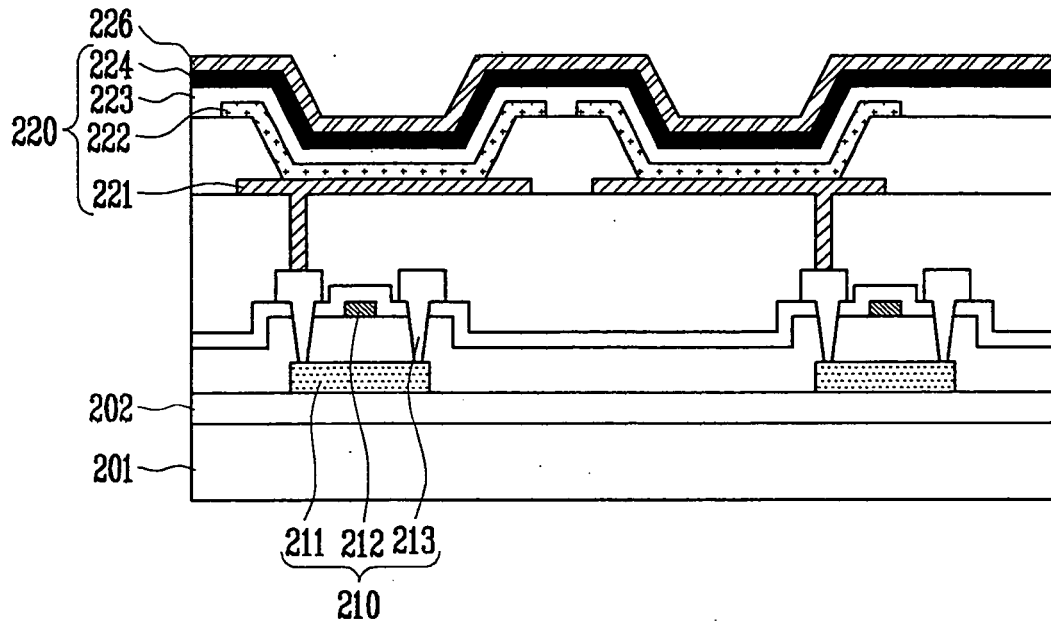


FIG. 6

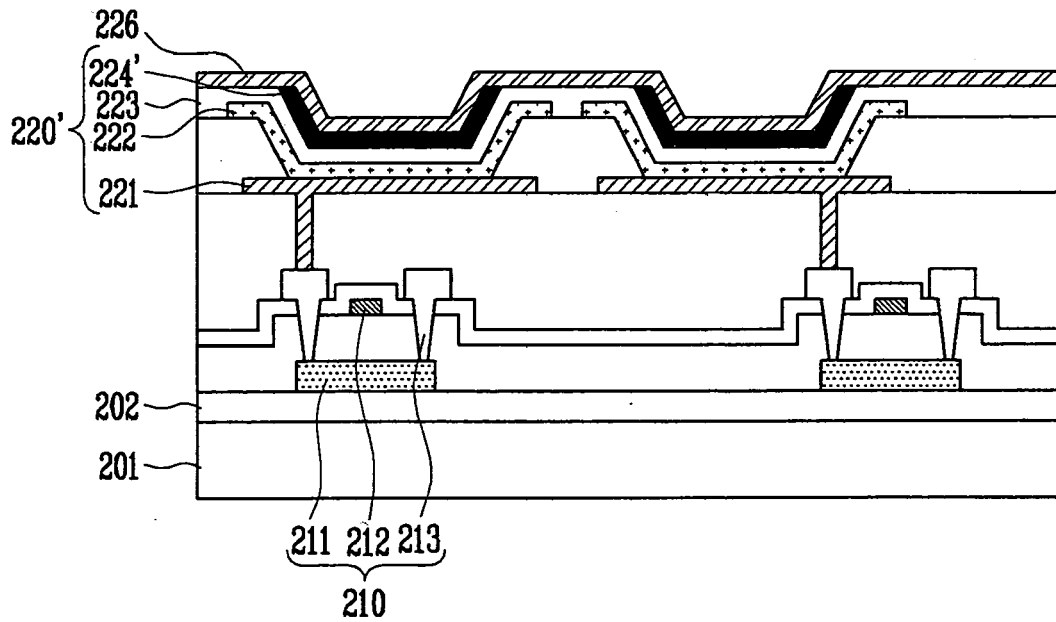




FIG. 7

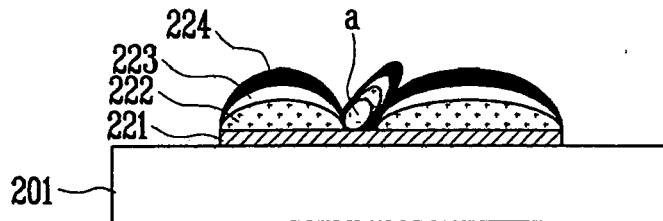


FIG. 8

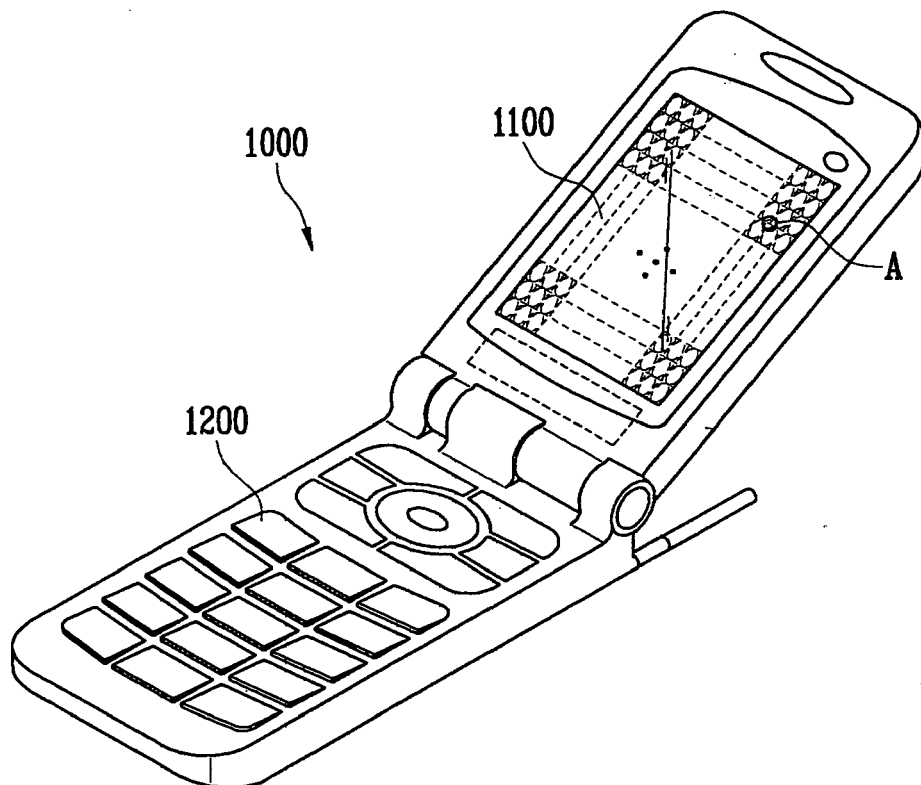


FIG. 9

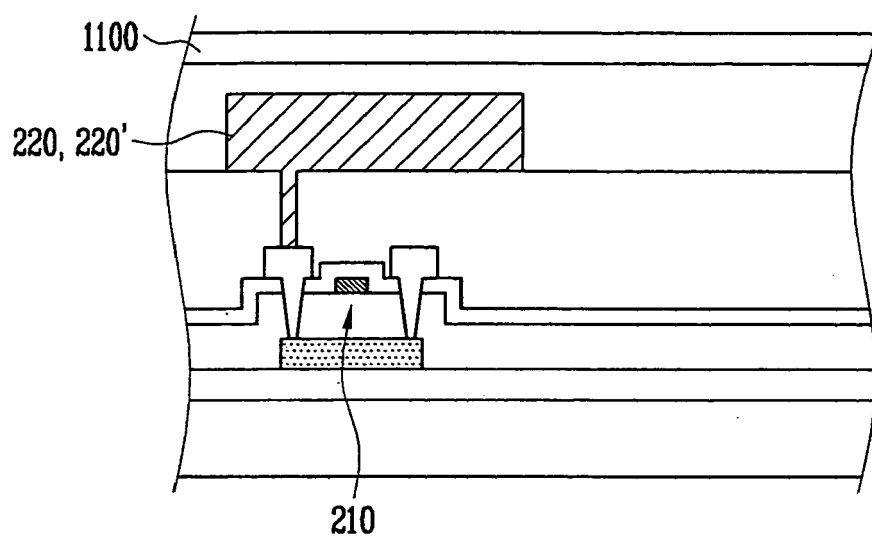


FIG. 10  
(RELATED ART)

